

MC10E122, MC100E122

5V ECL 9-Bit Buffer

The MC10E/100E122 is a 9-bit buffer. The device contains nine non-inverting buffer gates.

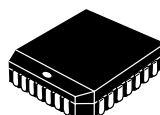
The 100 Series contains temperature compensation.

- 500 ps Max. Propagation Delay
- PECL Mode Operating Range: $V_{CC} = 4.2\text{ V}$ to 5.7 V with $V_{EE} = 0\text{ V}$
- NECL Mode Operating Range: $V_{CC} = 0\text{ V}$ with $V_{EE} = -4.2\text{ V}$ to -5.7 V
- Internal Input 50 K Ω Pulldown Resistors
- ESD Protection: Human Body Model; > 2 KV, Machine Model; > 200 V
- Meets or Exceeds JEDEC Spec EIA/JESD78 IC Latchup Test
- Moisture Sensitivity Level 1
For Additional Information, see Application Note AND8003/D
- Flammability Rating: UL 94 V-0 @ 0.125 in, Oxygen Index: 28 to 34
- Transistor Count = 111 devices



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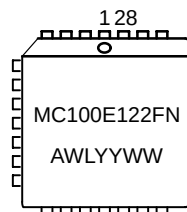
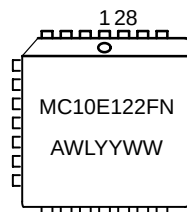
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**PLCC-28
FN SUFFIX
CASE 776**

A = Assembly Location
WL = Wafer Lot
YY = Year
WW = Work Week

MARKING DIAGRAMS



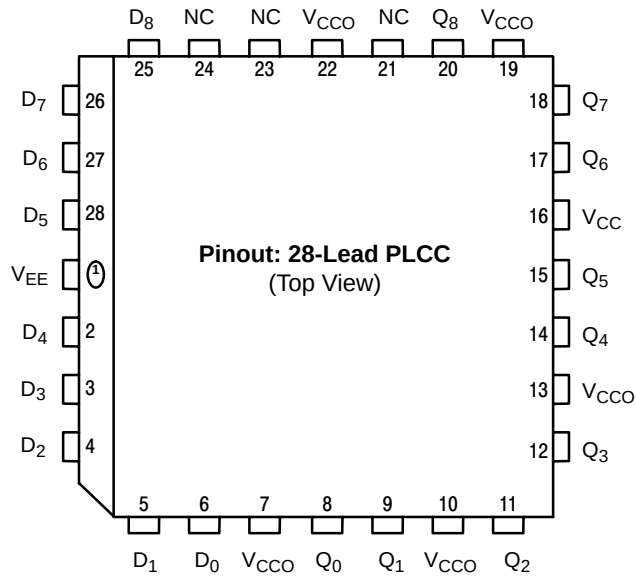
ORDERING INFORMATION

Device	Package	Shipping [†]
MC10E122FN	PLCC-28	37 Units/Rail
MC10E122FNR2	PLCC-28	500 Units/Reel
MC100E122FN	PLCC-28	37 Units/Rail
MC100E122FNR2	PLCC-28	500 Units/Reel

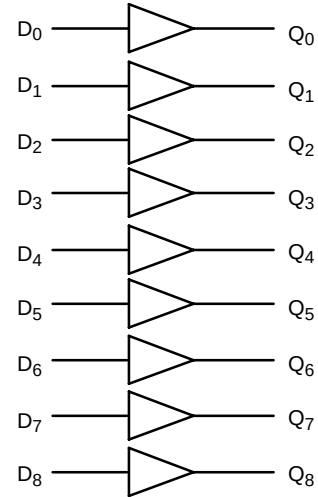
[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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LOGIC DIAGRAM AND PINOUT ASSIGNMENT



LOGIC DIAGRAM



* All V_{CC} and V_{CCO} pins are tied together on the die.

Warning: All V_{CC} , V_{CCO} , and V_{EE} pins must be externally connected to Power Supply to guarantee proper operation.

PIN DESCRIPTION

PIN	FUNCTION
$D_0 - D_8$	ECL Data Inputs
$Q_0 - Q_8$	ECL Data Outputs
V_{CC} , V_{CCO}	Positive Supply
V_{EE}	Negative Supply
NC	No Connect

MAXIMUM RATINGS (Note 1)

Symbol	Parameter	Condition 1	Condition 2	Rating	Units
V_{CC}	PECL Mode Power Supply	$V_{EE} = 0\text{ V}$		8	V
V_I	PECL Mode Input Voltage NECL Mode Input Voltage	$V_{EE} = 0\text{ V}$ $V_{CC} = 0\text{ V}$	$V_I \leq V_{CC}$ $V_I \geq V_{EE}$	6 -6	V V
I_{out}	Output Current	Continuous Surge		50 100	mA mA
T_A	Operating Temperature Range			0 to +85	°C
T_{stg}	Storage Temperature Range			-65 to +150	°C
θ_{JA}	Thermal Resistance (Junction to Ambient)	0 LFPM 500 LFPM	28 PLCC 28 PLCC	63.5 43.5	°C/W °C/W
θ_{JC}	Thermal Resistance (Junction to Case)	std bd	28 PLCC	22 to 26	°C/W
T_{sol}	Wave Solder	<2 to 3 sec @ 248°C		265	°C

1. Maximum Ratings are those values beyond which device damage may occur.

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10E SERIES PECL DC CHARACTERISTICS $V_{CCx}= 5.0\text{ V}$; $V_{EE}= 0.0\text{ V}$ (Note 2)

Symbol	Characteristic	0°C			25°C			85°C			Unit
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
I_{EE}	Power Supply Current		41	49		41	49		41	49	mA
V_{OH}	Output HIGH Voltage (Note 3)	3980	4070	4160	4020	4105	4190	4090	4185	4280	mV
V_{OL}	Output LOW Voltage (Note 3)	3050	3210	3370	3050	3210	3370	3050	3227	3405	mV
V_{IH}	Input HIGH Voltage	3830	3995	4160	3870	4030	4190	3940	4110	4280	mV
V_{IL}	Input LOW Voltage	3050	3285	3520	3050	3285	3520	3050	3302	3555	mV
I_{IH}	Input HIGH Current			200			200			200	μA
I_{IL}	Input LOW Current	0.5	0.3		0.5	0.25		0.3	0.2		μA

NOTE: Devices are designed to meet the DC specifications shown in the above table, after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse air flow greater than 500 lfpm is maintained.

2. Input and output parameters vary 1:1 with V_{CC} . V_{EE} can vary $-0.46\text{ V} / +0.06\text{ V}$.

3. Outputs are terminated through a 50 ohm resistor to $V_{CC} - 2$ volts.

10E SERIES NECL DC CHARACTERISTICS $V_{CCx}= 0.0\text{ V}$; $V_{EE}= -5.0\text{ V}$ (Note 4)

Symbol	Characteristic	0°C			25°C			85°C			Unit
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
I_{EE}	Power Supply Current		41	49		41	49		41	49	mA
V_{OH}	Output HIGH Voltage	-1020	-930	-840	-980	-895	-810	-910	-815	-720	mV
V_{OL}	Output LOW Voltage	-1950	-1790	-1630	-1950	-1790	-1630	-1950	-1773	-1595	mV
V_{IH}	Input HIGH Voltage	-1170	-1005	-840	-1130	-970	-810	-1060	-890	-720	mV
V_{IL}	Input LOW Voltage	-1950	-1715	-1480	-1950	-1715	-1480	-1950	-1698	-1445	mV
I_{IH}	Input HIGH Current			200			200			200	μA
I_{IL}	Input LOW Current	0.5	0.3		0.5	0.065		0.3	0.2		μA

NOTE: Devices are designed to meet the DC specifications shown in the above table, after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse air flow greater than 500 lfpm is maintained.

4. Input and output parameters vary 1:1 with V_{CC} . V_{EE} can vary $-0.46\text{ V} / +0.06\text{ V}$.

5. Outputs are terminated through a 50 ohm resistor to $V_{CC} - 2$ volts.

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100E SERIES PECL DC CHARACTERISTICS $V_{CCx} = 5.0\text{ V}$; $V_{EE} = 0.0\text{ V}$ (Note 6)

Symbol	Characteristic	0°C			25°C			85°C			Unit
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
I_{EE}	Power Supply Current		41	49		41	49		47	57	mA
V_{OH}	Output HIGH Voltage	3975	4050	4120	3975	4050	4120	3975	4050	4120	mV
V_{OL}	Output LOW Voltage	3190	3295	3380	3190	3255	3380	3190	3260	3380	mV
V_{IH}	Input HIGH Voltage	3835	3975	4120	3835	3975	4120	3835	3975	4120	mV
V_{IL}	Input LOW Voltage	3190	3355	3525	3190	3355	3525	3190	3355	3525	mV
I_{IH}	Input HIGH Current			200			200			200	μA
I_{IL}	Input LOW Current	0.5	0.3		0.5	0.25		0.5	0.2		μA

NOTE: Devices are designed to meet the DC specifications shown in the above table, after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse air flow greater than 500 lfpm is maintained.

6. Input and output parameters vary 1:1 with V_{CC} . V_{EE} can vary $-0.46\text{ V} / +0.8\text{ V}$.

7. Outputs are terminated through a 50 ohm resistor to $V_{CC} - 2\text{ volts}$.

100E SERIES NECL DC CHARACTERISTICS $V_{CCx} = 0.0\text{ V}$; $V_{EE} = -5.0\text{ V}$ (Note 8)

Symbol	Characteristic	0°C			25°C			85°C			Unit
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
I_{EE}	Power Supply Current		41	49		41	49		47	57	mA
V_{OH}	Output HIGH Voltage	-1025	-950	-880	-1025	-950	-880	-1025	-950	-880	mV
V_{OL}	Output LOW Voltage	-1810	-1705	-1620	-1810	-1745	-1620	-1810	-1740	-1620	mV
V_{IH}	Input HIGH Voltage	-1165	-1025	-880	-1165	-1025	-880	-1165	-1025	-880	mV
V_{IL}	Input LOW Voltage	-1810	-1645	-1475	-1810	-1645	-1475	-1810	-1645	-1475	mV
I_{IH}	Input HIGH Current			200			200			200	μA
I_{IL}	Input LOW Current	0.5	0.3		0.5	0.25		0.5	0.2		μA

NOTE: Devices are designed to meet the DC specifications shown in the above table, after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse air flow greater than 500 lfpm is maintained.

8. Input and output parameters vary 1:1 with V_{CC} . V_{EE} can vary $-0.46\text{ V} / +0.8\text{ V}$.

9. Outputs are terminated through a 50 ohm resistor to $V_{CC} - 2\text{ volts}$.

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AC CHARACTERISTICS $V_{CCX}= 5.0\text{ V}$; $V_{EE}= 0.0\text{ V}$ or $V_{CCX}= 0.0\text{ V}$; $V_{EE}= -5.0\text{ V}$ (Note 8)

Symbol	Characteristic	0°C			25°C			85°C			Unit
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
f_{MAX}	Maximum Toggle Frequency		800			800			800		MHz
t_{PLH} t_{PHL}	Propagation Delay to Output D to Q	150	350	500	150	350	500	150	350	500	ps
t_{SKEW}	Within-Device Skew D to Q (Note 11)		75			75			75		ps
t_{JITTER}	Random Clock Jitter (RMS)		< 1			< 1			< 1		ps
t_r t_f	Rise/Fall Times (20 - 80%)	300	425	800	300	425	800	300	425	800	ps

10.10 Series: V_{EE} can vary $-0.46\text{ V} / +0.06\text{ V}$.

100 Series: V_{EE} can vary $-0.46\text{ V} / +0.8\text{ V}$.

11. Within-device skew is defined as identical transitions on similar paths through a device.

12. Devices are designed to meet the AC specifications shown in the above table, after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse air flow greater than 500 lfpm is maintained.

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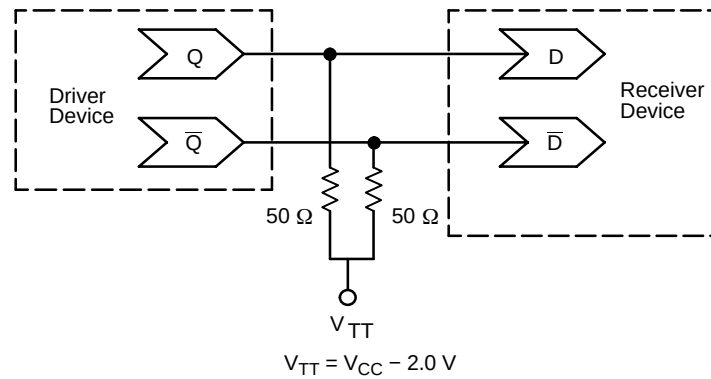


Figure 1. Typical Termination for Output Driver and Device Evaluation
(See Application Note AND8020 – Termination of ECL Logic Devices.)

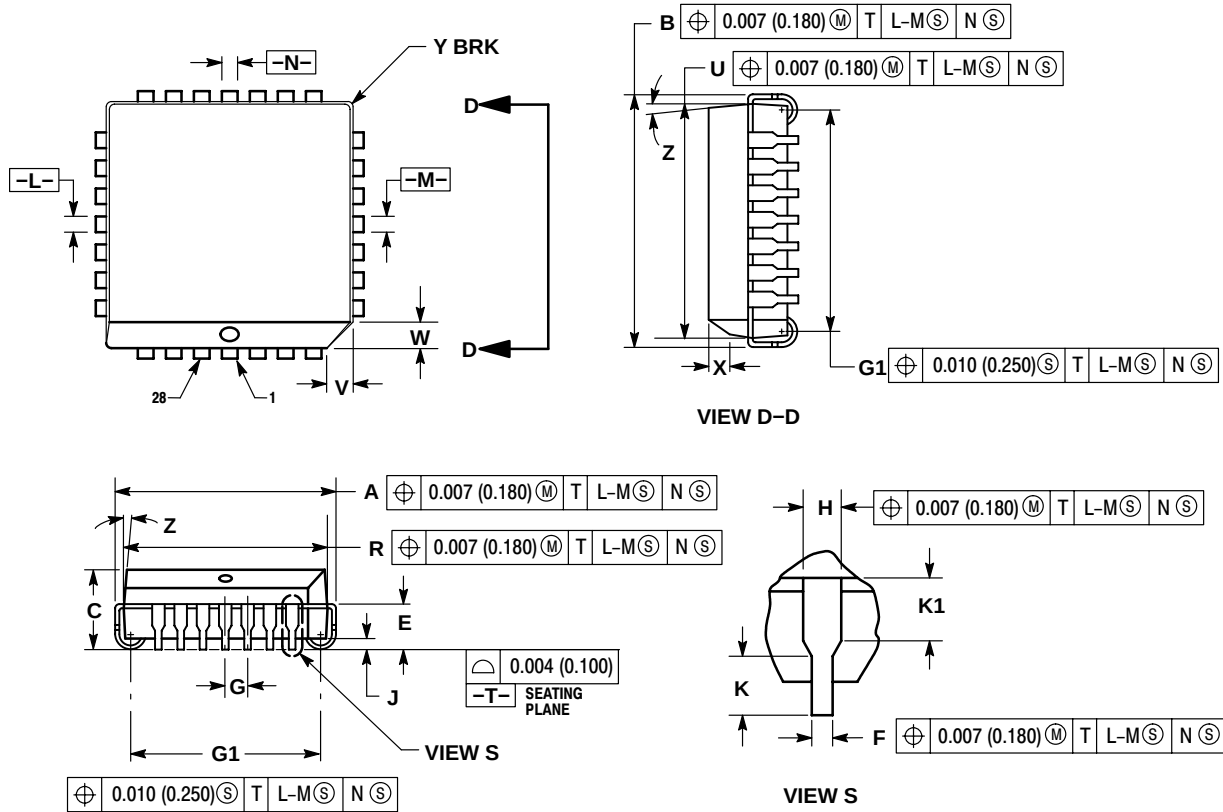
Resource Reference of Application Notes

- | | |
|----------------|---|
| AN1404 | – ECLinPS Circuit Performance at Non-Standard V_{IH} Levels |
| AN1405 | – ECL Clock Distribution Techniques |
| AN1406 | – Designing with PECL (ECL at +5.0 V) |
| AN1503 | – ECLinPS I/O SPICE Modeling Kit |
| AN1504 | – Metastability and the ECLinPS Family |
| AN1568 | – Interfacing Between LVDS and ECL |
| AN1596 | – ECLinPS Lite Translator ELT Family SPICE I/O Model Kit |
| AN1650 | – Using Wire-OR Ties in ECLinPS Designs |
| AN1672 | – The ECL Translator Guide |
| AND8001 | – Odd Number Counters Design |
| AND8002 | – Marking and Date Codes |
| AND8020 | – Termination of ECL Logic Devices |

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PACKAGE DIMENSIONS

PLCC-28
FN SUFFIX
PLASTIC PLCC PACKAGE
CASE 776-02
ISSUE E



NOTES:

- DATUMS -L-, -M-, AND -N- DETERMINED WHERE TOP OF LEAD SHOULDER EXITS PLASTIC BODY AT MOLD PARTING LINE.
- DIMENSION G1, TRUE POSITION TO BE MEASURED AT DATUM -T-, SEATING PLANE.
- DIMENSIONS R AND U DO NOT INCLUDE MOLD FLASH. ALLOWABLE MOLD FLASH IS 0.010 (0.250) PER SIDE.
- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: INCH.
- THE PACKAGE TOP MAY BE SMALLER THAN THE PACKAGE BOTTOM BY UP TO 0.012 (0.300). DIMENSIONS R AND U ARE DETERMINED AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY EXCLUSIVE OF MOLD FLASH, TIE BAR BURRS, GATE BURRS AND INTERLEAD FLASH, BUT INCLUDING ANY MISMATCH BETWEEN THE TOP AND BOTTOM OF THE PLASTIC BODY.
- DIMENSION H DOES NOT INCLUDE DAMBAR PROTRUSION OR INTRUSION. THE DAMBAR PROTRUSION(S) SHALL NOT CAUSE THE H DIMENSION TO BE GREATER THAN 0.037 (0.940). THE DAMBAR INTRUSION(S) SHALL NOT CAUSE THE H DIMENSION TO BE SMALLER THAN 0.025 (0.635).

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.485	0.495	12.32	12.57
B	0.485	0.495	12.32	12.57
C	0.165	0.180	4.20	4.57
E	0.090	0.110	2.29	2.79
F	0.013	0.019	0.33	0.48
G	0.050 BSC		1.27 BSC	
H	0.026	0.032	0.66	0.81
J	0.020	---	0.51	---
K	0.025	---	0.64	---
R	0.450	0.456	11.43	11.58
U	0.450	0.456	11.43	11.58
V	0.042	0.048	1.07	1.21
W	0.042	0.048	1.07	1.21
X	0.042	0.056	1.07	1.42
Y	---	0.020	---	0.50
Z	2° 10°		2° 10°	
G1	0.410	0.430	10.42	10.92
K1	0.040	---	1.02	---

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